

IDS-10-6-2003
10/678127

LIST OF REFERENCES CITED BY APPLICANT Form PTO-1449 <i>(Use several sheets if necessary)</i>	ATTY. DOCKET NO.: 4717-7400	APPLICATION NO.: 10/678127
Sheet 1 of 1	APPLICANT: Fabrice LETERTRE et al.	
FILING DATE: 6 October 2003		GROUP: 2822

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	CITE NO.	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
							YES	NO
MT	A	WO 02/37556	05/2002	PCT				

OTHER REFERENCES *(Including Author, Title, Date, Pertinent Pages, Etc.)*

MT	B	Jalaguier et al., "Transfer of thin InP films onto silicon substrate by proton implantation process," May, 1999
MT	C	R. Fornari et al., "Homogeneity of thermally annealed Fe-doped InP wafers," 1997
MT	D	A. Näser et al., "Thermal stability of the midgap acceptor rhodium in indium phosphide" 1995

EXAMINER <i>Michael Tri...</i>	DATE CONSIDERED 6/1/05
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*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.